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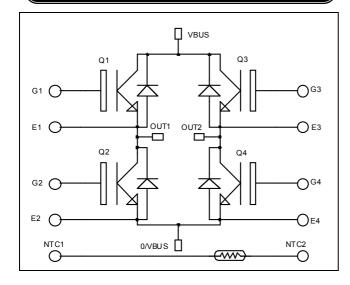








Full - Bridge Trench + Field Stop IGBT3 Power Module



G4 🛭

E4 🗓

E2 0

G2 🛭

O/VBUS

 $V_{CES} = 600V$ $I_{C} = 100A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



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OUT2

OUT1

NTC2 🛭

NTC1

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

₽ G3

8 E3

VBUS

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		
I_{C}	Continuous Collector Current	$T_C = 80$ °C	100	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	340	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	200A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		1.5	1.9	V
$V_{CE(sat)}$	Confector Emitter Saturation Voltage	$I_C = 100A$ $T_j = 150^{\circ}C$		1.7		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1.5 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		6100		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		390		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		190		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		115		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 100A$		225		ns
T_{f}	Fall Time	$R_G = 3.3\Omega$		55		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)		130		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		50		
$T_{d(off)} \\$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 100A$		300		ns
$T_{\rm f}$	Fall Time	$R_G = 3.3\Omega$		70		
Б	Turn on Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.4		ma I
Eon	Turn on Energy	$V_{\text{Bus}} = 300 \text{V}$ $T_{\text{j}} = 150^{\circ}\text{C}$		0.875		mJ
E	T 2ff F	$I_C = 100A$ $T_j = 25^{\circ}C$		2.5		ma I
E_{off}	Turn off Energy	$R_G = 3.3\Omega \qquad T_j = 150^{\circ}C$		3.5		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$			250 500	μΑ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		100		A
V	V_F Diode Forward Voltage $ I_F = 100A $ $V_{GE} = 0V$	$I_F = 100A$	$T_i = 25^{\circ}C$		1.6	2	V
v _F		$T_{i} = 150^{\circ}C$		1.5		V	
+	t _{rr} Reverse Recovery Time		$T_j = 25$ °C		125		ns
ι _{rr}		$T_{\rm j} = 150^{\circ}{\rm C}$		220		115	
0	D. Clare	$\begin{array}{c} I_F = 100A \\ V_R = 300V \\ di/dt = 2000A/\mu s \end{array}$	$T_j = 25^{\circ}C$		4.7		ıı.C
Q_{rr}	Reverse Recovery Charge		$T_{\rm j} = 150^{\circ}{\rm C}$		9.9		μС
Е	Reverse Recovery Energy	T	$T_j = 25$ °C		1.1		m I
$\mathrm{E_{r}}$			$T_{i} = 150^{\circ}C$		2.4		mJ



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

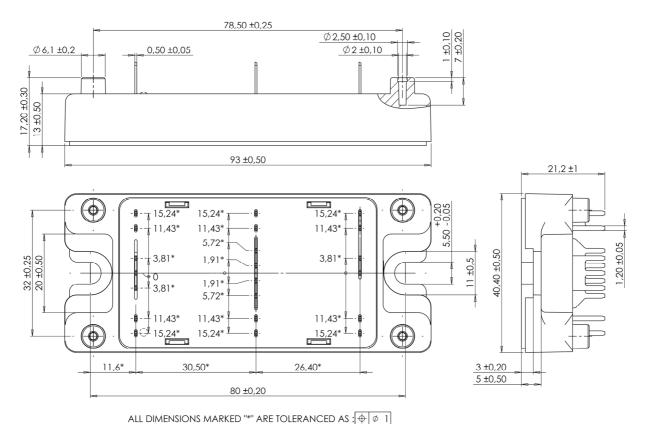
$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance IGBT Diode		IGBT			0.44	°C/W
			Diode			0.77	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

SP4 Package outline (dimensions in mm)

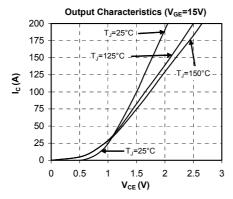


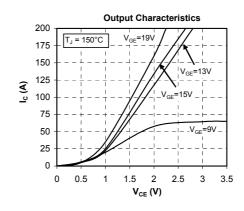
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

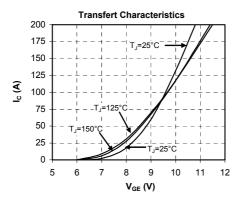
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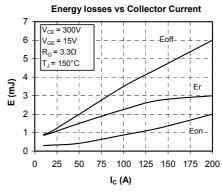


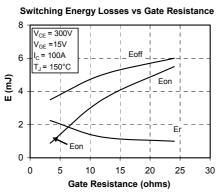
Typical Performance Curve

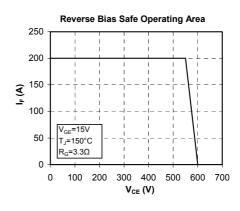


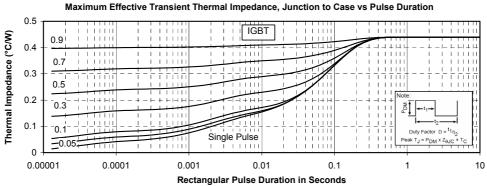




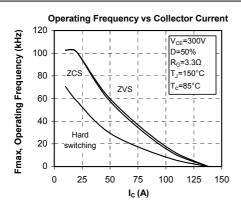


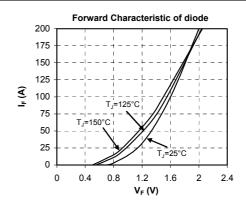


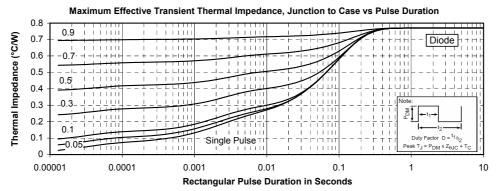














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